

FL14KM-12A

HIGH-SPEED SWITCHING USE

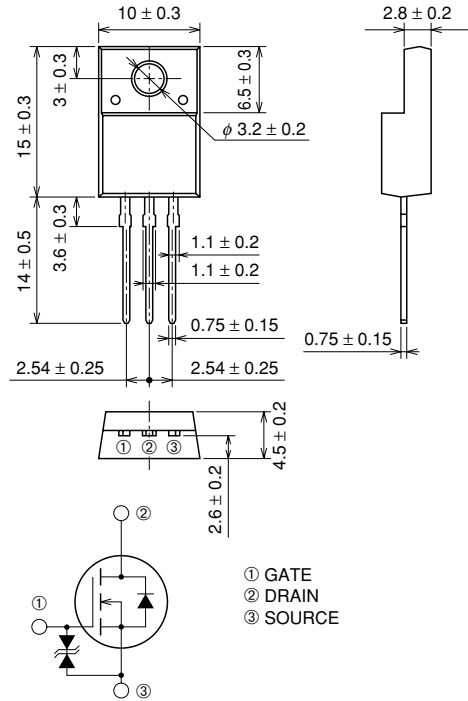
FL14KM-12A



- 10V DRIVE
- V_{DS} 600V
- $r_{DS(ON)}$ (MAX) 0.75Ω
- I_D 14A

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

SMPS, Inverter type fluorescent light sets, etc.

MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	600	V
V_{GSS}	Gate-source voltage	$V_{DS} = 0V$	± 30	V
I_D	Drain current		14	A
I_{DM}	Drain current (Pulsed)		42	A
I_{DA}	Avalanche current (Pulsed)	$L = 200\mu H$	14	A
P_D	Maximum power dissipation		40	W
T_{ch}	Channel temperature		$-55 \sim +150$	°C
T_{stg}	Storage temperature		$-55 \sim +150$	°C
V_{iso}	Isolation voltage	AC for 1minute, Terminal to case	2000	V
—	Weight	Typical value	2.0	g

ELECTRICAL CHARACTERISTICS (Tch = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	ID = 1mA, VGS = 0V	600	—	—	V
V (BR) GSS	Gate-source breakdown voltage	IG = ±100μA, VDS = 0V	±30	—	—	V
IGSS	Gate-source leakage current	VGS = ±25V, VDS = 0V	—	—	±10	μA
IDSS	Drain-source leakage current	VDS = 600V, VGS = 0V	—	—	1	mA
VGS (th)	Gate-source threshold voltage	ID = 1mA, VDS = 10V	2.0	3.0	4.0	V
rDS (ON)	Drain-source on-state resistance	ID = 7A, VGS = 10V	—	0.58	0.75	Ω
VDS (ON)	Drain-source on-state voltage	ID = 7A, VGS = 10V	—	4.06	5.25	V
yfs	Forward transfer admittance	ID = 7A, VDS = 10V	—	11	—	S
Ciss	Input capacitance	VDS = 25V, VGS = 0V, f = 1MHz	—	1600	—	pF
Coss	Output capacitance		—	210	—	pF
Crss	Reverse transfer capacitance		—	80	—	pF
td (on)	Turn-on delay time	VDD = 200V, ID = 7A, VGS = 10V, RGEN = RGS = 50Ω	—	30	—	ns
tr	Rise time		—	60	—	ns
td (off)	Turn-off delay time		—	290	—	ns
tf	Fall time		—	120	—	ns
VSD	Source-drain voltage	IS = 7A, VGS = 0V	—	1.5	2.0	V
Rth (ch-c)	Thermal resistance	Channel to case	—	—	3.13	°C/W